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# Orbital-Level Insights into Multifunctional Electrocatalysis of Transition-Metal Single Atoms Anchored on WS<sub>2</sub> Monolayers

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## **Support Information**

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**Note S1** Calculations of binding energy ( $E_b$ ) between the TM and WS<sub>2</sub>

The  $E_b$  was calculated to estimate the binding ability, which is defined as:

$$E_b = E(total) - E(WS_2) - E(TM)$$

Here, E(total) and  $E(WS_2)$  represent the total energies of the  $WS_2$  monolayer with and without the anchored atoms, respectively. E(TM) is the energy of the TM atom in vacuum. The more negative  $E_b$  represents a larger binding strength.

#### **Note S2** The hydrogen evolution reaction (HER)

The total HER can be written as,  $H^+ + e^- \rightarrow 1/2H_2$ . This reaction occurs at the electrode, which supplies electrons and provides an intermediate adsorption site. The mechanism typically involves two steps: \* + H<sup>+</sup> + e<sup>-</sup>  $\rightarrow$  \*H (Volmer step) for the first step, then 2\*H  $\rightarrow$  H<sub>2</sub> (Tafel step) or \*H + H<sup>+</sup> + e<sup>-</sup>  $\rightarrow$  \* + H<sub>2</sub> (Heyrovsky step) for the second step.

The Gibbs free energy ( $\Delta G(H)$ ) of hydrogen atom adsorption is defined as  $\Delta G(H) = \Delta E_H + \Delta E_{ZPE}$  -  $T\Delta S$ , where  $\Delta E_H$  is the hydrogen chemisorption energy,  $E_{ZPE}$ , and  $T\Delta S$  are the zero-point energy and the entropy contribute to the  $\Delta G(H)$ , respectively. As it is well established that  $E_{ZPE}$  -  $T\Delta S = 0.24$  eV  $^1$ , the expression for  $\Delta G(H)$  can be simplified to  $\Delta G(H) = \Delta E_H + 0.24$  eV, as previous studies do.<sup>2-3</sup> Based on Norskov's assumption,

the exchange current (i<sub>0</sub>) expressions, 
$$i_0 = \frac{-ek_0}{1 + \exp(-\Delta G(H) / k_B T)}$$
 and

$$i_0 = \frac{-ek_0}{1 + \exp(\Delta G(H) / k_B T)}$$
, were used for  $\Delta G(H) \le 0$  and  $\Delta G(H) > 0$ , respectively. <sup>1, 4</sup>

As there is no experimental data available, the rate constant,  $k_0$ , was set to 1, as it was treated in the references.<sup>5-7</sup>

**Note S3** The four-electron transfer pathways of the oxygen reduction reaction (ORR) and oxygen evolution reaction (OER) under acidic conditions (pH = 0).

Both associative and dissociative mechanisms<sup>8</sup> of ORR have been explored. Since the OER and ORR are thermodynamically and mechanistically reversible, sharing the same intermediates but proceeding in opposite directions, only the ORR reaction pathways are presented below.

Associative mechanism:

\* + O<sub>2</sub> + H<sup>+</sup> + 
$$e^{-} \rightarrow$$
 \*OOH, (a)  
\*OOH + H<sup>+</sup> +  $e^{-} \rightarrow$  \*O + H<sub>2</sub>O, (b)  
\*O + H<sup>+</sup> +  $e^{-} \rightarrow$  \*OH, (c)  
\*OH + H<sup>+</sup> +  $e^{-} \rightarrow$  \* +H<sub>2</sub>O, (d)

Dissociative mechanism:

\* 
$$+O_2 + H^+ + e^- \rightarrow *O + *OH, (a')$$

\* $O + *OH + H^+ + e^- \rightarrow *OH + *OH, (b')$ 

\* $O + *OH + H^+ + e^- \rightarrow *O + H_2O, (b'')$ 

\* $OH + *OH + H^+ + e^- \rightarrow *OH + H_2O, (c')$ 

\* $O + H^+ + e^- \rightarrow *OH, (c)$ 

\* $OH + H^+ + e^- \rightarrow *H_2O, (d)$ 

The adsorption free energy of the \*OH ( $\Delta$ G(OH)), \*OOH ( $\Delta$ G(OOH)), and \*O ( $\Delta$ G(O)) can be evaluated by

$$\Delta G(OH) = G(*OH) + 1/2G(H_2) - G^* - G(H_2O),$$
  

$$\Delta G(OOH) = G(*OOH) + 3/2G(H_2) - G^* - 2G(H_2O),$$
  

$$\Delta G(O) = G(*O) + G(H_2) - G^* - G(H_2O)$$

The free-energy change,  $\Delta G$ , for each step of ORR with the associative mechanism was obtained by setting  $\Delta G(O_2) = 4.92$  eV and  $\Delta G(H_2O) = 0$  eV at 298 K as follows:

$$\begin{split} \Delta G_a &= G(*OOH) - G*-G(O_2) - 1/2G(H_2) \\ &= G(*OOH) - G*-G(O_2) - 1/2G(H_2) + 2G(H_2) - 2G(H_2) \\ &= G(*OOH) - G*+3/2 \ G(H_2) - G(O_2) - 2G(H_2) \\ &= G(*OOH) - G*+3/2 \ G(H_2) - 2G(H_2O) - 4.92 \\ &= \Delta G(OOH) - 4.92 \\ \Delta G_b &= G(*O) + G(H_2O) - G(*OOH) - 1/2G(H_2) \\ &= G(*O) + G(H_2) - G*-G(H_2O) - G(*OOH) - 3/2G(H_2) + G*+2G(H_2O) \\ &= \Delta G(O) - \Delta G(OOH) \\ \Delta G_c &= G(*OH) - G(*O) - 1/2G(H_2) \\ &= G(*OH) + 1/2G(H_2) - G*-G(H_2O) - G(*O) - G(H_2) + G*+G(H_2O) \\ &= \Delta G(OH) - \Delta G(O) \\ \Delta G_d &= G(H_2O) + G*-1/2G(H_2) - G(*OH) \\ &= -\Delta G(OH) \end{split}$$

Then the overpotentials for ORR ( $\eta_{ORR}$ , V) can be calculated by the following equation<sup>9</sup>:

$$\eta_{\rm ORR} = 1.23 \text{ V} + \text{max} (\Delta G_a, \Delta G_b, \Delta G_c, \Delta G_d)/e$$

The overpotentials for OER ( $\eta_{OER}$ , V) are defined by <sup>10-11</sup>:

$$\eta_{OER} = \max(-\Delta G_a, -\Delta G_b, -\Delta G_c, -\Delta G_d)/e - 1.23 \text{ V}$$

### **Note S4** Calculation of the volcano peak for ORR and OER<sup>12</sup>

As shown in Figs. 4a and 4b, strong linear scaling relationships were observed between the adsorption free energies of \*O ( $\Delta$ G(O)) and \*OOH ( $\Delta$ G(OOH)) with respect to \*OH ( $\Delta$ G(OH)), with correlation coefficients (R²) of 0.97 for  $\Delta$ G(OOH) vs.  $\Delta$ G(OH) and 0.90 for  $\Delta$ G(O) vs.  $\Delta$ G(OH), respectively, as follows:

$$\Delta G(OOH) = 0.84\Delta G(OH) + 2.97 (R^2 = 0.97)$$

$$\Delta G(O) = 1.39\Delta G(OH) + 0.78 (R^2 = 0.90)$$

According to Table S4, the potential-determining step (PDS) of ORR for most systems is the formation of the second H<sub>2</sub>O molecule, except for Pd@WS<sub>2</sub>, where the formation of \*OOH is the PDS.

When the formation of the second H<sub>2</sub>O molecule is the PDS, the overpotential for the ORR can be calculated as:

$$\eta_{ORR} = \Delta G_d/e + 1.23 \text{ V}$$
$$= -\Delta G(OH)/e + 1.23 \text{ V}$$

When the formation of \*OOH is the PDS, the ORR overpotential is:

$$\eta_{ORR} = \Delta G_a/e + 1.23 \text{ V}$$

$$= (\Delta G(OOH) - 4.92)/e + 1.23 \text{ V}$$

At the volcano peak, these two expressions yield the same  $\eta_{ORR}$ , from which the optimal  $\Delta G(OH)$  and corresponding  $\eta_{ORR}$  at the volcano apex are determined to be 1.06 eV and 0.17 V, respectively.

Similarly, for the OER, Table S4 shows that the PDS is typically the reaction of \*O with a second H<sub>2</sub>O molecule to generate \*OOH and H<sup>+</sup>, except for Co@WS<sub>2</sub> and Pd@WS<sub>2</sub>. For Co@WS<sub>2</sub>, the PDS is the formation of O<sub>2</sub>, but the energy difference between O<sub>2</sub> formation and \*OOH formation is within 0.1 eV, so the \*OOH formation step is reasonably treated as the PDS. For Pd@WS<sub>2</sub>, the dissociation of \*OH into \*O and H<sup>+</sup>

is the PDS.

When the formation of \*OOH and H<sup>+</sup> is the PDS, the OER overpotential is calculated as:

$$\eta_{OER} = -\Delta G_b/e - 1.23 \text{ V}$$
$$= \Delta G(OOH) - \Delta G(O) - 1.23 \text{ V}$$

When the dissociation of \*OH is the PDS, the OER overpotential is:

$$\eta_{OER} = -\Delta G_c/e - 1.23 \text{ V}$$
$$= \Delta G(O) - \Delta G(OH) - 1.23 \text{ V}$$

At the volcano peak, both expressions give the same  $\eta_{OER}$ , resulting in an optimal  $\Delta G(OH)$  of 1.50 eV and a corresponding  $\eta_{OER}$  of 0.14 V.

**Note S5** Calculations of formation energy ( $E_f$ ) and the dissolution potential ( $U_{diss}$ ) for TM@WS<sub>2</sub>.

The thermodynamic stability and electrochemical stability were evaluated by the formation energy ( $E_f$ ) and the dissolution potential ( $U_{diss}$ ), defined as<sup>13</sup>:

$$E_f = E(total) - E(WS_2) - E(TM-bulk)$$

$$U_{\rm diss} = U^0 - E_{\rm f}/{\rm ne}$$

Where E(total) and E(WS<sub>2</sub>) are the total energies of WS<sub>2</sub> with and without the TM atom, respectively, and E(TM-bulk) is the energy of the TM atom in their bulk.  $U^0$  denotes the standard dissolution potential of bulk TM, and n is the number of electrons involved in the dissolution. The values of  $U^0$  and n comes from the previous literature.<sup>13</sup>

 $\label{eq:table S1} \textbf{Table S1} \ \text{Zero-point energy corrections and entropic contributions (at 298.15 \ K) to the free energies.}$ 

species	$\Delta E_{ZPE}$ (eV)	TΔS (eV)
H <sub>2</sub> O	0.56	0.67
$H_2$	0.27	0.40
*OOH	0.42	0.216
*OH	0.32	0.09
*O	0.05	0.11

**Table S2** Charge transfer amounts (Q(TM), e) of TM atoms, the Fe-S bond length (d(Fe-S), Å) and the adsorption free energies ( $\Delta$ G, eV) of the O, OH and OOH. A negative Q(TM) indicates electron transfer from the TM atom to the WS<sub>2</sub> substrate.

	Q(TM)	d(Fe-S)	ΔG(OOH)	ΔG(O)	ΔG(OH)	ΔG(H)
U=0	-0.56	2.145 / 2.145 / 2.145	2.92	0.27	-0.63	0.07
U=1	-0.56	2.153 / 2.152 / 2.152	2.83	0.25	-0.65	0.002
U=2	-0.55	2.165 / 2.163 / 2.163	2.50	0.25	-0.67	-0.07
U=3	-0.53	2.170 / 2.169 / 2.169	2.46	0.24	-0.72	-0.17
U=4	-0.52	2.174 / 2.174 / 2.174	2.39	0.20	-0.80	-0.30

**Table S3** Binding energies ( $E_b$ , eV) of TM atoms at the S-top ( $E_b$ (S)), hollow ( $E_b$ (H)), and W-top sites ( $E_b$ (T)) on WS<sub>2</sub>, formation energy ( $E_f$ , eV), and dissolution potential ( $U_{diss}$ , V) of TM@WS<sub>2</sub>. Also listed are the d-band centers ( $\varepsilon_d$ , eV) and charge transfer amounts (Q(TM), e) of TM atoms. A negative Q(TM) indicates electron transfer from the TM atom to the WS<sub>2</sub> substrate.

	E <sub>b</sub> (S)	$E_{\rm b}({ m H})$	E <sub>b</sub> (T)	Ef	$U_{ m diss}$	<b>€</b> d	Q(TM)
Fe	-0.92	-2.07	-2.44	3.01	-1.96	-1.13	-0.56
Co	-1.49	-2.51	-3.00	2.64	-1.60	-1.13	-0.43
Ni	-2.30	-3.39	-3.91	1.67	-1.10	-1.04	-0.36
Ru	-2.07	-2.52	-3.47	4.10	-1.59	-1.54	-0.31
Rh	-2.41	-2.68	-3.49	3.09	-0.94	-1.63	-0.18
Pd	-2.00	-2.09	-2.45	1.87	0.01	-1.70	-0.15
Os	-1.81	-2.18	-3.13	5.91	0.10	-1.64	-0.30
Ir	-2.48	-3.00	-3.44	4.52	-0.35	-1.99	-0.11
Pt	-2.88	-2.59	-3.23	3.10	-0.37	-2.26	-0.024

**Table S4** H adsorption free energy ( $\Delta G(H)$ , eV), electron transfer to the adsorbed H atom ( $\Delta Q(H)$ , e), integrated crystal orbital Hamilton population between TM and H (ICOHP(TM–H)), adsorption free energy of the second H atom ( $\Delta G_{sec}(H)$ , eV), and energy barrier for H<sub>2</sub> formation ( $\Delta E_{H2}$ , eV) on TM@WS<sub>2</sub>.

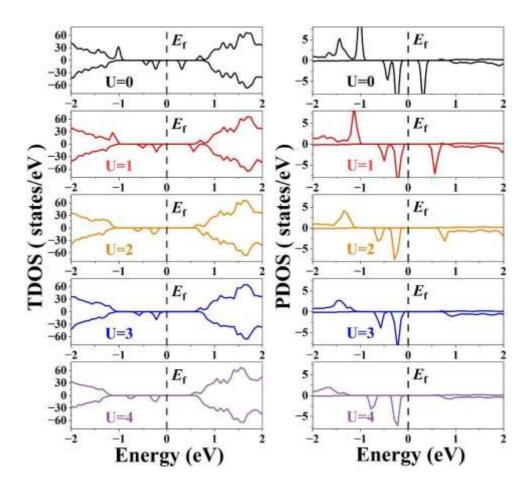
	ΔG(H)	Q(H)	ICOHP(TM-H)	$\Delta G_{Sec}(H)$	<b>ДЕ</b> н2
Fe	0.07	0.39	-2.10	-0.21	0.59
Co	0.11	0.14	-2.29	-0.52	0.81
Ni	0.68	0.23	-1.96		
Ru	-0.19	0.16	-2.58	-0.08	0.68
Rh	-0.27	0.07	-2.65		
Pd	0.83	0.13	-2.26		
Os	-0.64	0.21	-2.84		
Ir	-0.76	0.11	-2.93		
Pt	-0.01	0.08	-2.47	-0.87	1.29

 $\textbf{Table S5} \ \text{The potential-determining steps (PDS)} \ \text{for the ORR and OER on } TM@WS_2.$ 

	PDS (ORR)	PDS (OER)
Fe	$*OH+H2O+H++e-\rightarrow 2H2O$	$*O+H_2O+2H^++2e^- \rightarrow *OOH+3H^++3e^-$
Co	$*OH+H2O+H++e-\rightarrow 2H2O$	$*OOH+3H^++3e^- \rightarrow O_2+4H^++4e^-$
Ni	$*OH+H2O+H++e-\rightarrow 2H2O$	$*O+H_2O+2H^++2e^- \rightarrow *OOH+3H^++3e^-$
Ru	$*OH+H2O+H++e-\rightarrow 2H2O$	$*O+H_2O+2H^++2e^- \rightarrow *OOH+3H^++3e^-$
Rh	$*OH+H2O+H++e-\rightarrow 2H2O$	$*O+H_2O+2H^++2e^- \rightarrow *OOH+3H^++3e^-$
Pd	$O_2+4H^++4e^- \rightarrow *OOH+3H^++3e^-$	$*OH+H_2O+H^++e^- \rightarrow *O+H_2O+3H^++3e^-$
Ir	$*OH+H2O+H++e-\rightarrow 2H2O$	$*O+H_2O+2H^++2e^- \rightarrow *OOH+3H^++3e^-$
Pt	$*OH+H2O+H++e-\rightarrow 2H2O$	$*O+H_2O+2H^++2e^- \rightarrow *OOH+3H^++3e^-$

**Table S6** Adsorption free energies of \*OOH ( $\Delta G(OOH)$ , eV), \*O ( $\Delta G(O)$ , eV), and \*OH ( $\Delta G(OH)$ , eV), along with the calculated overpotentials for ORR ( $\eta_{ORR}$ , V) and OER ( $\eta_{OER}$ , V). Also listed are the magnetic moment on the TM site upon \*OH adsorption ( $M_B$ ,  $\mu_B$ ) and the amount of charge transferred to the \*OH species ( $\Delta Q(OH)$ , e).

	ΔG(OOH)	ΔG(O)	ΔG(OH)	ηorr	ηOER	M <sub>B</sub>	Q(OH)
Fe	2.92	0.27	-0.63	1.86	1.33	2.39	0.51
Co	2.77	0.60	-0.22	1.45	0.92	1.55	0.44
Ni	3.50	1.88	0.58	0.65	0.32	0.64	0.44
Ru	2.75	0.10	-0.21	1.44	1.34	1.54	0.45
Rh	3.29	1.17	0.62	0.61	0.8	1.04	0.43
Pd	4.13	2.80	1.32	0.44	0.33	0.41	0.39
Os		-1.24	-0.62	1.85	4.15	0.45	
Ir	2.76	0.31	-0.20	1.43	1.14	0.96	0.40
Pt	3.57	1.67	0.60	0.63	0.58	0.41	0.36



**Fig. S1** Total DOS (left) and Fe-3*d* PDOS (right) of the Fe@WS<sub>2</sub> system.

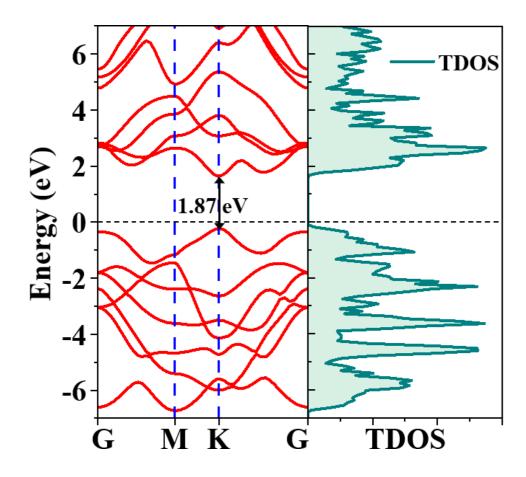


Fig. S2 Calculated band structure and total density of states (TDOS) of pristine  $WS_2$ .

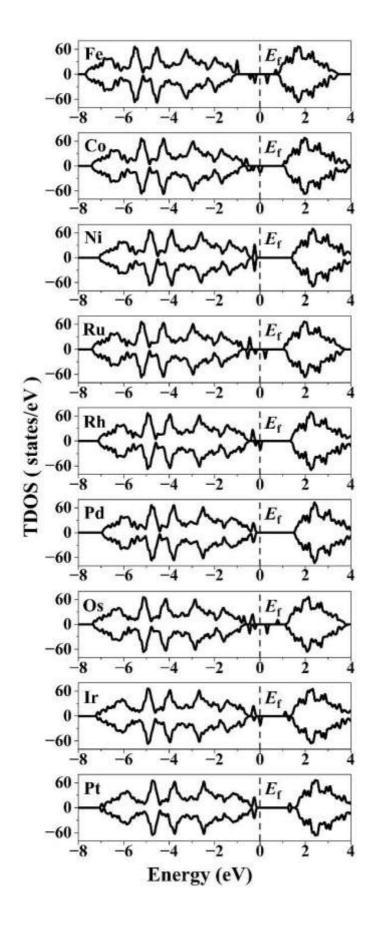
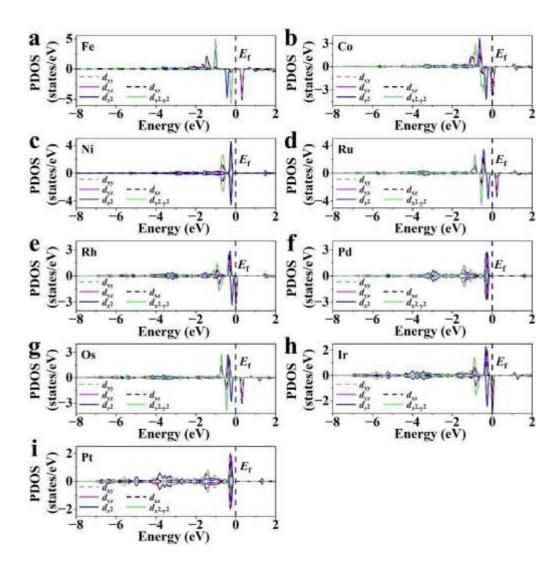


Fig. S3 Total density of states (TDOS) of  $TM@WS_2$  systems.



**Fig. S4** Projected density of states (PDOS) of TM@WS<sub>2</sub> systems: (a) Fe, (b) Co, (c) Ni, (d) Ru, (e) Rh, (f) Pd, (g) Os, (h) Ir, and (i) Pt.

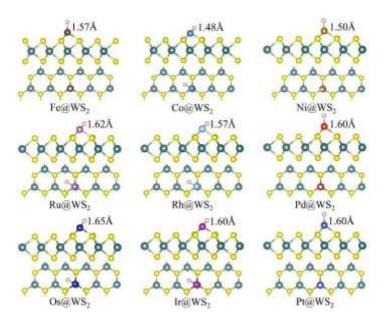
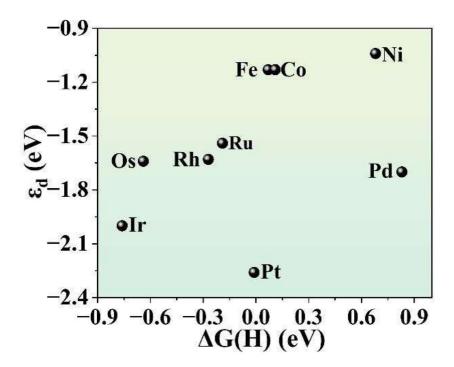


Fig. S5 Optimized atomic structures of H adsorption on TM@WS $_2$  with key structural parameters labeled (in Å).



**Fig. S6** Correlation between the *d*-band center  $(\varepsilon_d)$  of TM atoms and the hydrogen adsorption free energy  $(\Delta G(H))$  on TM@WS<sub>2</sub>.

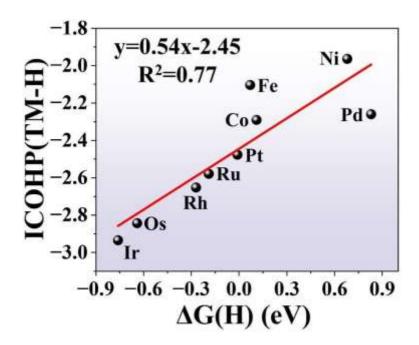
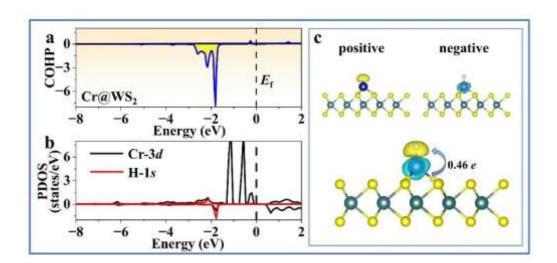
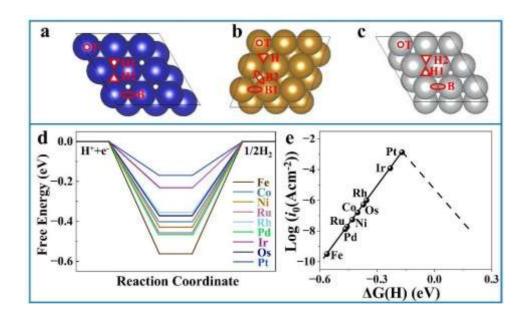


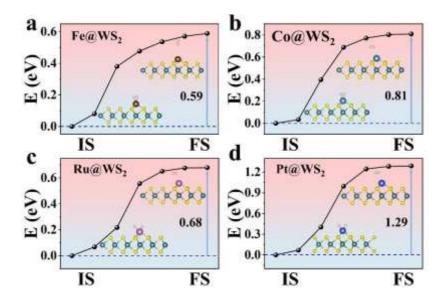
Fig. S7 Correlation between the integrated crystal orbital Hamilton population of the TM–H bond and the hydrogen adsorption free energy ( $\Delta G(H)$ ) on TM@WS<sub>2</sub>.



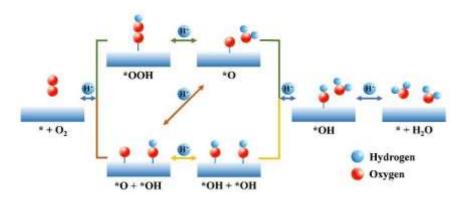
**Fig. S8** (a) COHP analysis of the Cr–H interaction, (b) projected density of states (PDOS) of Cr-3d and H-1s, and (c) charge density difference (CDD) for Cr@WS<sub>2</sub>. The isosurface value is set to 0.005 e bohr<sup>-3</sup> for CDD.



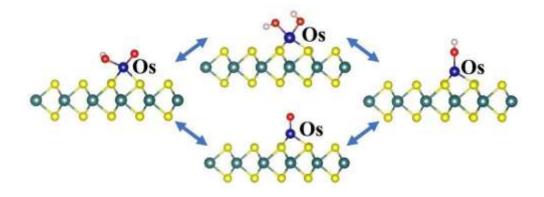
**Fig. S9** (a–c) Schematic illustration of the top two atomic layers and representative adsorption sites on (a) hcp (0001), (b) bcc (110), and (c) fcc (111) metal surfaces. (d) Free energy diagrams of the HER on TM@WS<sub>2</sub> systems. (e) Volcano plot of the exchange current density ( $i_{\theta}$ ) as a function of the hydrogen adsorption free energy ( $\Delta G(H)$ ).



**Fig. S10** Energy barriers for the formation of physisorbed  $H_2$  via the Tafel mechanism from two adsorbed hydrogen atoms on (a) Fe@WS<sub>2</sub>, (b) Co@WS<sub>2</sub>, (c) Ru@WS<sub>2</sub>, and (d) Pt@WS<sub>2</sub>.



 $\label{eq:Fig.S11} \textbf{Fig.S11} \ \text{Schematic illustration of the possible reaction pathways for the ORR and OER}$  on  $TM@WS_2$  catalysts.



 $\textbf{Fig. S12} \ \text{The ORR and OER pathways on Os@WS}_2.$ 

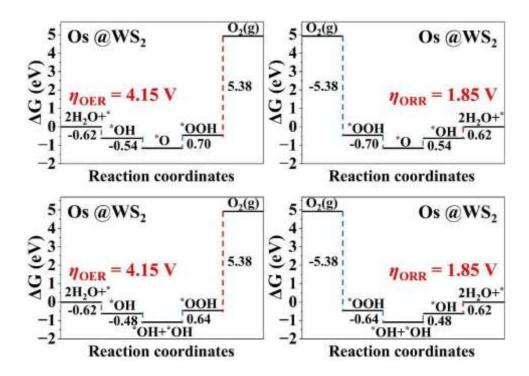


Fig. S13 Gibbs free energy change ( $\Delta G$ ) for each elementary step involved in the OER and ORR on Os@WS<sub>2</sub>.

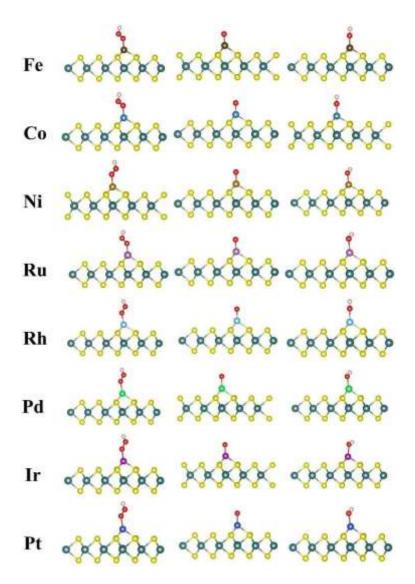
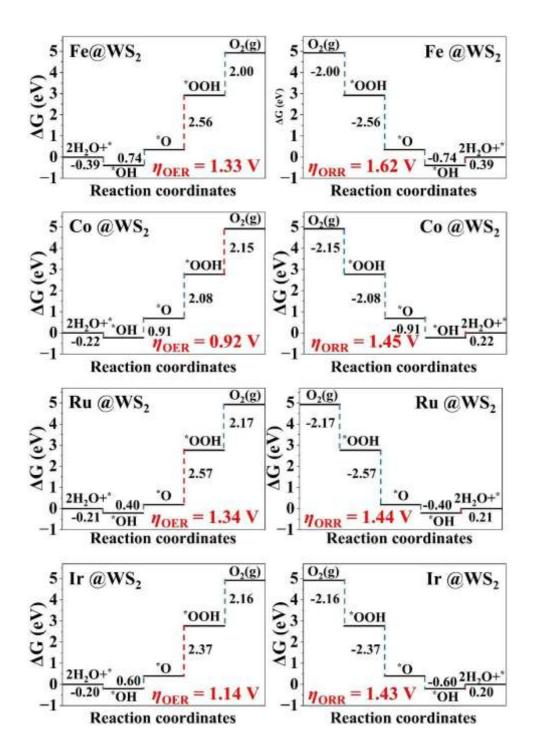
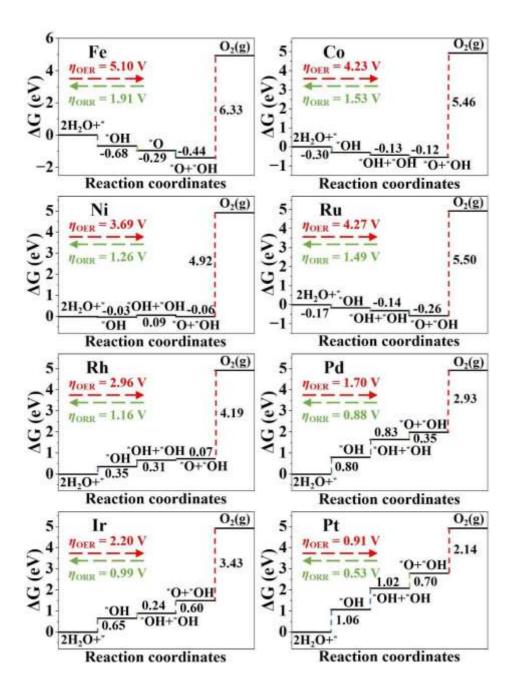


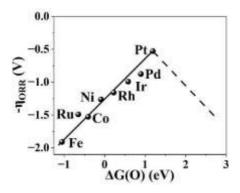
Fig. S14 Optimized atomic structures of \*O, \*OH, and \*OOH adsorbed on TM@WS2.



**Fig. S15** Gibbs free energy change ( $\Delta G$ ) for each elementary step involved in the OER and ORR on Fe@WS<sub>2</sub>, Co@WS<sub>2</sub>, Ru@WS<sub>2</sub>, Ir@WS<sub>2</sub>.



**Fig. S16** Gibbs free energy changes ( $\Delta G$ ) for each elementary step involved in the OER and ORR on the bcc Fe (110) surface, fcc Ni, Pt, Pd, Ir, and Rh (111) surfaces, and hcp Ru, Os, and Co (0001) surfaces. Note that although the associative mechanism of ORR may also occur on bulk Pt, Ir, Pd, and Rh, its catalytic performance is inferior to that of the dissociative mechanism; thus, it is not further discussed here.



**Fig. S17** Relationship between the ORR overpotential ( $\eta_{ORR}$ ) and  $\Delta G(O)$ .

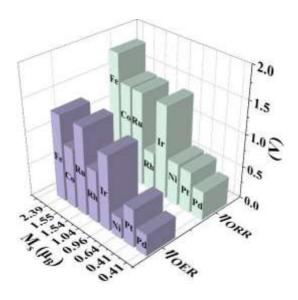


Fig. S18 Correlation between the magnetic moment on the TM site upon \*OH adsorption  $(M_B, \mu_B)$  and the overpotentials for OER and ORR on TM@WS<sub>2</sub>.

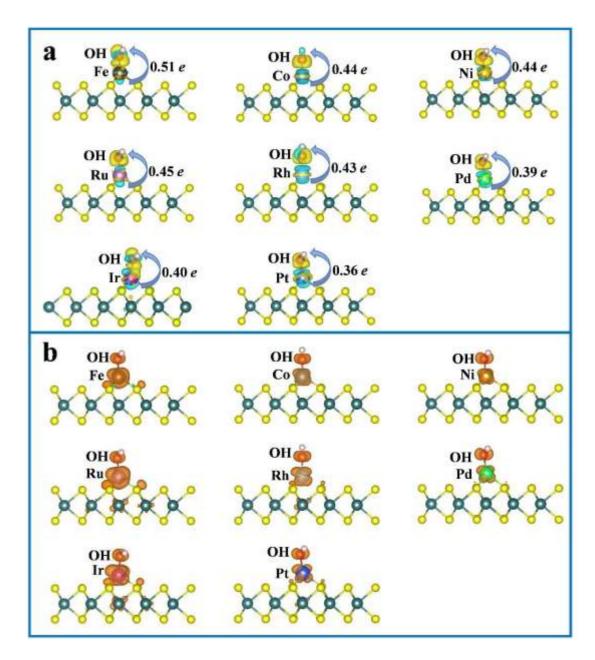
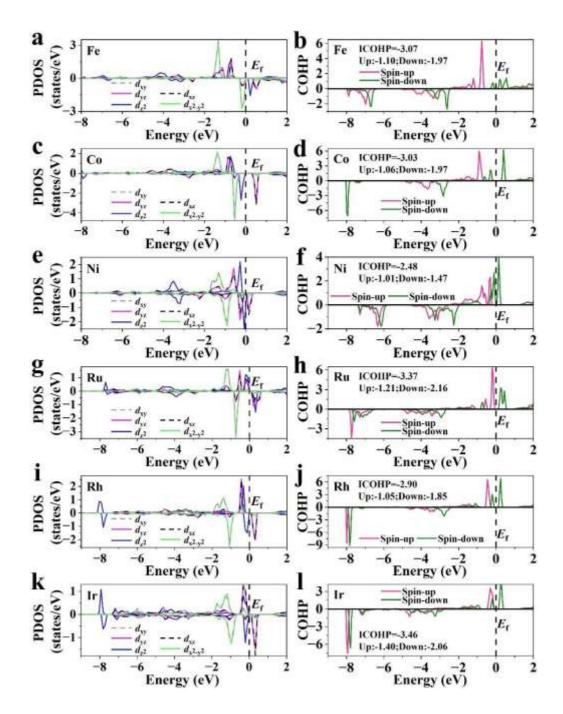
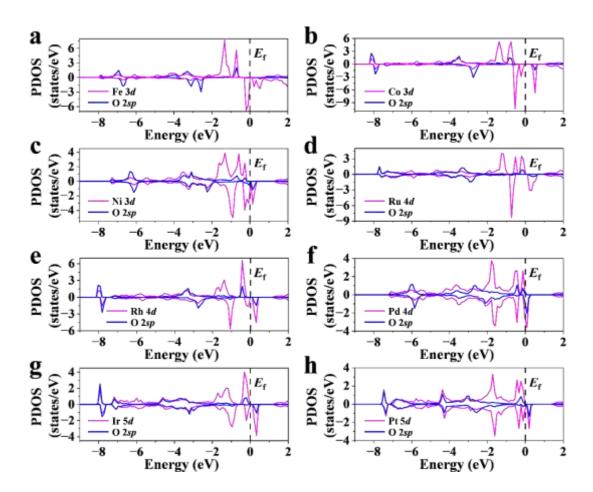


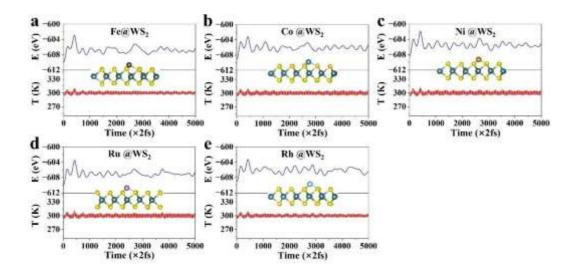
Fig. S19 (a) Charge density difference and (b) spin density distribution of  $TM@WS_2$  with adsorbed \*OH.



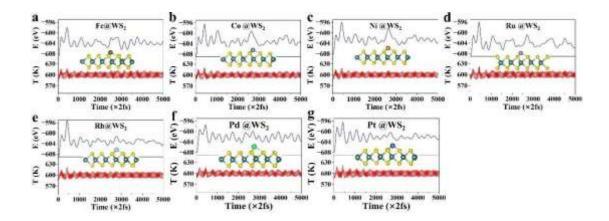
**Fig. S20** Projected density of states and crystal orbital Hamilton population of TM@WS $_2$  systems upon \*OH adsorption: (a, b) Fe, (c, d) Co, (e, f) Ni, (g, h) Ru, (i, j) Rh, and (k, l) Ir.



**Fig. S21** Projected density of states (PDOS) of the *d* orbitals of TM atoms and the O 2*p* orbitals of the TM@WS<sub>2</sub> with adsorbed OH. Panels correspond to (a) Fe@WS<sub>2</sub>, (b) Co@WS<sub>2</sub>, (c) Ni@WS<sub>2</sub>, (d) Ru@WS<sub>2</sub> and (e) Rh@WS<sub>2</sub>, (f) Pd@WS<sub>2</sub>, (g) Ir@WS<sub>2</sub>, and (h) Pt@WS<sub>2</sub>, respectively.



**Fig. S22** Ab initio molecular dynamics (AIMD) simulations at 600 K for (a) Fe@WS<sub>2</sub>, (b) Co@WS<sub>2</sub>, (c) Ni@WS<sub>2</sub>, (d) Ru@WS<sub>2</sub>, and (e) Rh@WS<sub>2</sub>, respectively.



**Fig. S23** Ab initio molecular dynamics (AIMD) simulations at 600 K for (a) Fe@WS<sub>2</sub>, (b)  $Co@WS_2$ , (c) Ni@WS<sub>2</sub>, (d) Ru@WS<sub>2</sub>, (e) Rh@WS<sub>2</sub>, (f) Pd@WS<sub>2</sub>, (g) Pt@WS<sub>2</sub>, respectively, respectively.

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